

REMARKS

In the Office Action, claims 1-2 were withdrawn from consideration, and claims 3 - 7 were rejected. Claims 1 and 2 have been canceled, claims 3 - 7 have been amended, and new claims 8 - 14 have been added. Upon entrance of this Response, claims 3 - 14 will be pending in the present application. Reconsideration is respectfully requested.

The drawings are amended to conform to the specification.

Applicant has amended the specification to improve clarity of expression, more clearly refer to the individual drawings, and correct minor typographical errors. Applicant has also amended claims 3 - 7 solely to enhance their clarity of expression and not to overcome any rejections or for reasons of patentability. No new matter has been added.

In paragraph 4 of the Office Action, claim 7 was rejected under 35 U.S.C. § 102(b) as being anticipated by U.S. Patent No. 5,560,837 to TREUBA. The Examiner rejected claim 7, in part, because TRUEBA teaches “exposing and developing layer by patterned light (Col. 6, lines 4 - 9).” The paragraph cited by the Examiner disclosed,

Next, a layer of negative photoresist 409 is applied, then exposed through the transparent substrate 102 (“backside” exposure; represented by arrows labeled “UV”) (FIG 4D). The donuts 401 act as a mask such that when the photoresist is then developed, pillars of photoresist 409 remain on the structure (FIG. 4E).

From this paragraph two things may be understood: (1) a “negative photoresist” is being used and as such the portions of the photoresist exposed by the light are not removed by the light or by the development process, and (2) light exposure itself does not result in the removal of any photoresist but instead “development” after exposure results in the removal of unexposed portions of the photoresist. Though use of light or lack thereof can be considered to limit or facilitate the removal of photoresist in a development process, the light itself does not cause removal. These teachings are in direct contradiction to what is being claimed. Hence this rejection is traversed. Claim 7 as examined recites, in part,

exposing said layer to patterned light to substantially remove said layer from said support in exposed areas.

First, from this language it is clear that the “exposed areas” are removed and not the unexposed areas as taught by TRUEBA. As such, TRUEBA cannot meet the claim. Second,

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it is the “exposing said layer to pattern light...” that achieves the purpose “to substantially remove said layer ...” Since in accordance with this element of the claim the “patterned light” causes the removal, not a development process, and as TRUEBA does not disclose such a removal process, TRUEBA cannot meet or make obvious this claim.

Applicant has amended claim 7 to enhance its clarity and not for reasons of patentability. Claim 7 has been amended, in part, to read,

exposing said layer to patterned light to substantially [the remove] cause removal of said layer from said support in exposed areas.

Based on the above, Applicant respectfully requests reconsideration of the rejection of claim 7.

New claims 8-14 have been added. Claims 8 and 9 depend from claim 7 and hence are similarly allowable. Independent claim 10 recites a method including in part:

forming a surface relief pattern on a surface of the support, wherein the pattern has positive and negative features;
applying a flowable conformable material over the surface of the support containing the relief pattern;
pressing the flowable conformable material against the surface of the support to remove at least a portion of any conformable material that is located over positive features of the surface relief pattern;
solidifying and bonding the flowable conformable material to the support;
removing any residual conformable material that is located over the positive features of the surface relief pattern; and
removing the surface relief pattern from the support while leaving the solidified conformable material bonded to the support..

Support for claim 10 and claims 11 - 14, which depend from claim 10, is provided at, e.g., page 16, line 24 to page 17, line 12. No new matter has been added. Applicant respectfully submits that TREUBA does not anticipate claims 8 - 14. Thus, claim 10 and claims 11 - 14, which depend therefrom, are patentable over TREUBA.

In Section 6 of the Office Action, the Examiner rejected claims 3 - 6 under the judicially created doctrine of obviousness-type double patenting, as being unpatentable over claims 1, 2, 10 and 11 of U.S. Patent No. 6,027,630. Applicant traverses this rejection as inappropriate and requests the Examiner to reconsider the rejection and to withdraw it. These claims were originally presented in the parent of this application (09/055,183) as claims 58 - 61. This parent application is the application that issued as US Patent 6,027,630. These claims were not prosecuted in the parent application as that application was subjected to a

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seven way restriction with claims 58 - 61 forming Group VI while the claims that issued in the '630 patent formed Group V. As such the present double patenting rejection is believed improper under 35 U.S.C. §121, last sentence, and reconsideration and withdrawal of this rejection is earnestly solicited.

CONCLUSION

In this Response, unelected claims 1 and 2 have been canceled, claims 3 - 7 have been amended, and new claims 8 - 14 have been added. In view of the foregoing comments, Applicant respectfully submits that each of the outstanding rejections has been overcome and that claims 3 - 14 are in condition for allowance. The Examiner is invited to telephone Applicant's Attorney at (408) 453-9200, if such would advance the prosecution of this case.

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ATTACHMENT A

The paragraph starting at page 1, line 7 is amended as follows:

This is a divisional of U.S. [application serial no.] Patent Application No. 09/055,183, filed April 3, 1998, now U.S. Patent No. 6,027,630; which in turn [(pending). This application] claims priority to U.S. Provisional Application No. 60/043,742 filed on April 4, 1997.

The paragraph starting at page 1, line 11 is amended as follows:

Microfabrication processes (also referred to as micromachining) are being developed and refined for eventual application to the manufacture of complex devices including machines and instrumentation. These processes are being directed to the production of machines of miniaturized devices having features in the range of a few microns and in some cases features in the submicron range, some of which currently exist on a macroscopic scale.

The paragraph starting at page 1, line 17 is amended as follows:

Microfabrication processes include: bulk micromachining, in which material is removed from regions of a substrate; surface micromachining, in which a thin conformal structural layer and one or more sacrificial layers are deposited onto a substrate; and LIGA, which generates 2.5-D extruded shapes by molding materials around metals molds which were formed by the metals being electrodeposited within openings in thick synchrotron-processed photoresists. These processes are used to produce structures of simple geometries (e.g., they can be defined by 1-4 different cross sections), and are usually customized for each application.

The paragraph starting at page 3, line 21 is amended as follows:

In other aspects, the present invention is directed to the calculation, storage and retrieval of cross section geometry of a three dimensional object for generation of patterned masks reflecting that geometry and for use in an electroplating method. The data and control processes of various embodiments of the invention can be implemented by a software application program executed in a general purpose computing system.

The paragraph starting at page 3, line 26 is amended as follows:

The data and control processes of various embodiments of the invention can be embodied in an electroplating method implemented via the application program and also in an

article of manufacture, in the form of a data storage medium, that stores application program code arranged to carry out that method upon execution by a processor.

The paragraph starting at page 4, line 5 is amended as follows:

The electroplating methods of various embodiments of the invention can be used to fabricate devices of freeform geometry including high aspect ratio devices, hollow devices with internal features, devices with cantilevered and “chandelier” geometries, and functional assemblies of interconnected, stationary or moving parts (i.e., devices fabricated in an assembled state). The electroplating articles, apparatus, and methods also are particularly useful in mass production of devices.

The paragraph starting at page 4, line 11 is amended as follows:

Other features and advantages of various aspects of the invention will be apparent from the following description of the preferred embodiments thereof, and from the claims.

The paragraph starting at page 4, line 19 is amended as follows:

Figs. 3a-3d are [is a] diagrams of a first embodiment of a method for forming an electroplating article;

The paragraph starting at page 4, line 21 is amended as follows:

Figs. 4a-4e are [is a] diagrams of a second embodiment of a method for forming an electroplating article;

The paragraph starting at page 4, line 23 is amended as follows:

Figs. 5a-5e are [is a] diagrams of a third embodiment of a method for forming an electroplating article;

The paragraph starting at page 4, line 25 is amended as follows:

Figs. 6a-6d are [is a] diagrams of a fourth embodiment of a method for forming an electroplating article;

The paragraph starting at page 4, line 27 is amended as follows:

Figs. 7a-7f are [is a] diagrams of a fifth embodiment of a method for forming an electroplating article;

The paragraph starting at page 4, line 29 is amended as follows:

Figs. 8a-8e are [is a] diagrams of a sixth embodiment of a method for forming an electroplating article;

The paragraph starting at page 5, line 1 is amended as follows:

Figs. 9a-9c are [is a] diagrams of a seventh embodiment of a method for forming an electroplating article;

The paragraph starting at page 5, line 3 is amended as follows:

Figs. 10a-10c are [is a] diagrams of a method for forming a deposit according to an electroplating method of an embodiment of the invention;

The paragraph starting at page 5, line 5 is amended as follows:

Figs. 11a-11m are [is a] diagrams of a method according to [a first embodiment of] the electroplating method of an embodiment of the invention;

The paragraph starting at page 5, line 7 is amended as follows:

Figs. 12a-12c are [is a] diagrams of a method according to [a second embodiment of] the electroplating method of an embodiment of the invention;

The paragraph starting at page 5, line 9 is amended as follows:

Figs. 13a-13i are [is a] diagrams of a method for fabricating an element on an integrated circuit;

The paragraph starting at page 5, line 11 is amended as follows:

Figs. 14a-14e are [is a] diagrams of a method for assembling elements fabricated together;

The paragraph starting at page 5, line 12 is amended as follows:

Figs. 15a-15b are [is a] diagrams of an element manufactured according to [one embodiment of] the electroplating method of an embodiment of the invention;

The paragraph starting at page 5, line 14 is amended as follows:

Figs. 16a-16d are views taken in cross section of elements manufactured according to one embodiment of the invention;

The paragraph starting at page 5, line 20 is amended as follows:

Fig. 19 is a top view of a portion of an electroplating apparatus of an embodiment of the invention;

The paragraph stating at page 5, line 21 is amended as follows:

Fig. 20 is a top view of a portion of an electroplating apparatus according to an [third] embodiment [of the electroplating apparatus] of the present invention;

The paragraph starting at page 5, line 23 is amended as follows:

Fig. 21 is a top view of a portion of an electroplating apparatus according to an [fourth] embodiment [of the electroplating apparatus] of the present invention;

The paragraph starting at page 5, line 25 is amended as follows:

Fig. 22 is a view taken in cross section of [one embodiment of] an electroplating article holder of an embodiment of the present invention;

The paragraph starting at page 5, line 27 is amended as follows:

Fig. 23 is a view taken in cross section of [a second embodiment of] an electroplating apparatus of an embodiment of the present invention;

The paragraph starting at page 6, line 1 is amended as follows:

Fig. 25 is a view taken in cross section of [a third embodiment of] a portion of an electroplating apparatus of an embodiment of the invention;

The paragraph starting at page 6, line 7 is amended as follows:

Fig. 28 is a functional block diagram of a computing system configured for calculation of cross sections of a three dimensional structure and for driving an electroplating apparatus of an embodiment of the present invention;

The paragraph starting at page 6, line 15 is amended as follows:

Figs. 32a-32d are [is a] diagrams of an electroplating method employing more than one article according to a third embodiment of [the electroplating article of] the invention.

The paragraph starting at page 6, line 18 is amended as follows:

The [invention] embodiments feature[s] electroplating methods, apparatus and articles that enable the manufacture of elements having complex structures. The electroplating

methods include selective electroplating of layers that may include both structural materials (e.g., metals) and support (i.e., sacrificial) materials; and subsequent removal (e.g., by etching, melting, or electrolytically dissolving) of the support materials. The structural material remaining after removal of the support material defines an element such as a microscopic or mesoscopic device. The electroplating methods employ electroplating articles that include a patterned conformable mask, optionally adhered to a support such as an electrode or a porous medium.

The paragraph starting at page 6, line 27 is amended as follows:

In general, various embodiments of the invention feature[s] electroplating articles for use in electroplating methods. The electroplating method occurs in an electroplating apparatus that includes an electroplating bath filled with electrolyte, an anode, and a cathode. The electrolyte contains metal ions and, optionally, other additives. The anode can be part of the electroplating article, as described below, or can be located at a distance from the article. Throughout this application, the substrate to be plated functions as the cathode unless otherwise specified. To simplify the description, the materials are referred to as metals and similar features are indicated with the same reference numerals.

The paragraph starting at page 7, line 5 is amended as follows:

Referring to Fig. 1, electroplating article[s] 4, of a preferred embodiment of the invention includes a patterned conformable mask 6 adhered to a support 8. The electroplating article can also be only a patterned conformable mask (i.e. without a support). The support can be a porous medium (e.g., a filter), an anode, and combinations thereof. The article can include a plurality of different mask patterns on a single support. The different mask patterns can be contacted by a substrate in a predetermined sequence to sequentially plate a plurality of metal layers where each metal layer has a pattern corresponding to the complement of the mask pattern contacted, to form a multi-layered element. Referring to Fig. 2, electroplating article 4 can include one or more edge masks [3] 13 on the outer surface of the article, for confining the metal being plated.

The paragraph starting at page 7, line 15 is amended as follows:

Contact between the electroplating article and the substrate to be plated is made by pressing the patterned mask against the substrate using a well-controlled, uniform pressure. The appropriate masking pressure will prevent flash (i.e., the deposition of metal in the area

covered by the mask), and will prevent distortion of the features defined by the mask. When the electroplating article is removed from contact with the substrate, the mask remains adhered to the support and thus remains part of the electroplating article.

The paragraph starting at page 7, line 21 is amended as follows:

A variety of methods can be used to improve release of the mask from the substrate to be plated so as to prevent delamination of the mask from the support[;]: for example, gradually peeling the electroplating article (if flexible) off of the substrate optionally with the aid of a dull blade; adding a non-stick/lubricating compound to the electrolyte; coating the mask surface with a non-stick composition (e.g., sputtered polytetrafluoroethylene); and vibration (e.g., ultrasound).

The paragraph starting at page 8, line 19 is amended as follows:

The patterned mask is preferably substantially planar and smooth to enable conformance to the substrate to be plated. The mask is capable of being patterned with negative and positive features of varying dimensions (e.g., 10-25 um or smaller, such as submicron), preferably with no mask residue blocking the negative features of the mask pattern. The pattern of the mask includes apertures (i.e., negative features) extending through the mask thickness and defined by one or more [side walls] sidewalls of the mask. The mask features preferably have a substantially planar wall profile and may have a slight wall angle. The wall angle may be [(e.g.,) slightly divergent toward the substrate to be plated, i.e. the negative features are slightly larger at the substrate than at the support()]. Such wall angles may aid in separating the mask from the substrate and may aid in facilitating re-contacting the mask to the substrate in the presence of an existing deposit.

The paragraph starting at page 8, line 28 is amended as follows:

The mask can be compound so as to include [one or] more than one layer[s] of material, e.g., a relatively rigid layer ([i.e.] e.g., a high aspect ratio photoresist, e.g., SU-8 commercially available from MicroChem Corporation [and] or synchrotron-processed polymethylmethacrylate), and a conformable layer. Another example of a useful rigid layer is a positive photoresist such as Clariant AZ4620, which can be patterned by exposing it to ultraviolet light through the patterned conformable layer.

The paragraph starting at page 9, line 4 is amended as follows:

Examples of useful masking compositions for conformable portions of the mask include elastomers such as, e.g., polydimethylsiloxane (i.e., silicone rubber) commercially available, e.g., under the trade designation Sylgard from Dow-Corning (e.g., Sylgard 182 and 184), and under the trade designation RMS-033 from Gelest. The masking compositions can include other additives, e.g., photoinitiators, fillers, and hydrogen getters.

The paragraph starting at page 9, line 10 is amended as follows:

The porous medium has interconnected pores and is permeable to ions and additives present in electrolyte compositions. The porous medium can have one or more layers of varying porosity. The porous medium preferably has a pore size considerably finer than the minimum negative feature of the mask. The pores are preferably uniform in open area, e.g., the open area of any 20 μm square of the medium is consistent to 1%. Particularly useful porous mediums may be porous mediums that are useful [, when used] as filters, and particularly those that have a particle retention rating in the range of 0.3-3 μm . For those porous mediums that include multiple porous layers, each porous layer can vary in porosity and pore size, with the porous medium in closest proximity to the substrate to be plated exhibiting the above characteristics. The surfaces of the porous medium that contact the mask should be sufficiently flat and smooth to ensure that the surface of the adhered mask that contacts the substrate to be plated is also flat and smooth.

The paragraph starting at page 12, line 1 is amended as follows:

In general, methods for forming electroplating articles include applying a solid mask or liquid masking composition to a support, i.e., an anode, a porous medium and combinations thereof. The solid mask can be patterned prior or subsequent to attachment to the support. Liquid masking compositions can be patterned on a non-porous substrate (e.g., inert material, or a material that can be dissolved or melted (e.g., substrates of plastic, lacquer, or low melting point alloy)), cured ([i.e.] e.g., crosslinked, polymerized, hardened, solidified, gelled, and combinations thereof), and attached to a support or patterned and solidified directly on the support.

The paragraph starting at page 12, line 16 is amended as follows:

A variety of methods can be used to maintain or improve adhesion of the mask to a porous medium. These methods include melting the mask while pressing it into the porous

medium resulting in a mechanical interlocking of the mask with the porosity of the porous medium, and applying an adhesive composition between the mask and the porous medium. Adhesion of the mask to the porous medium can also be enhanced by employing an adhesive that is a meltable material (e.g., glass), which can be dry deposited (e.g., sputtered) onto the surface of the patterned mask. When using an adhesive composition, it is preferable to employ methods that confine the adhesive composition to the areas located between the mask and the support ([i.e.] e.g., preventing the adhesive from bridging a negative feature that is only a few microns wide).

The paragraph starting at page 12, line 26 is amended as follows:

Liquid masking compositions [has] have a tendency to soak into (i.e., uncontrollably absorb into) the pores of a porous medium. A variety of methods can be employed to reduce “soak in” in regions of the porous medium that are to remain porous. Examples of suitable methods for preventing soak in include: (1) supplying pressurized air to one side of the porous medium; (2) treating the porous medium with a temporary filler composition that soaks in and fills the pores and then solidifies to form a barrier to penetration of the liquid masking composition; and (3) treating the porous medium with a temporary filler composition that is immiscible with and denser than the liquid masking composition. The surface of the porous medium can be abraded after infiltrating the pores with filler composition to expose uncoated and unfilled surfaces allowing direct adhesion of the mask to the support. The filler composition can be dissolved or otherwise removed from the porous medium after the liquid masking composition has been cured to a solid.

The paragraph starting at page 13, line 11 is amended as follows:

Referring to Figs. 3a-3d, one example of a method for rendering a porous medium temporarily nonporous using a filler composition includes: spinning a thin layer of a liquid filler composition 132 onto a relatively flat surface 131 (e.g., a silicon wafer) (preferably the thickness of the filler composition layer is adjusted so as to fill the pores of the porous medium to a predetermined height); contacting a first surface 136 of porous medium 130 to the spun-on filler composition 132 (Fig. 3a)[,]; allowing filler composition 132 to seep into the pores of the porous medium to a predetermined [depth] height (Fig. 3b); solidifying the filler composition 132; and applying (e.g., by spinning on) a sufficient amount of liquid masking composition 134 to a second surface 138 of the porous medium 130 opposite the first

surface 136 through which filler composition 132 entered the porous medium 130. Liquid masking composition 134 is applied so as to produce a layer of masking composition of desired thickness on the surface of the porous medium. The remainder of the liquid masking composition 134 can seep into the porous medium (for purposes of adhesion) only to the surface of the solidified filler 132 (Fig. 3c). The method further includes curing the masking composition 134; removing solidified filler 132; etching the negative features of the mask through the layer of porous medium 130 that is saturated with masking composition 134 to at least a depth at which the solidified filler 134 existed (Fig. 3d).

The paragraph starting at page 14, line 14 is amended as follows:

Another approach to preventing soak in involves forming a barrier layer at or near the surface of the porous medium. After processing, the barrier layer (and optionally, some of the porous medium) is removed from the negative features of the mask, so as to expose the porosity of the porous medium. Optionally, to improve adhesion of the mask to the support, the regions of the barrier layer that will correspond to the positive features of the mask can be removed prior to application of the mask. The barrier layer can be removed using various techniques including, e.g., chemical etching, dry etching, ion milling, laser machining, and melting (e.g., for thermoplastic based barriers). The barrier layer can also be formed by applying another material to the surface of the porous substrate, e.g., (1) by laminating a film of a solid material, such as dry film photoresist onto the porous medium; (2) by applying a liquid barrier layer, preferably of high viscosity, using one of the techniques discussed above that restrict soak-in volume; (3) by coating the porous medium with a thin layer of powder and melting the powder layer so as to form a non-porous coating; (4) by depositing a barrier film by vacuum evaporation, sputtering, CVD, or other process; and (5) by using combinations thereof.

The paragraph starting at page 14, line 29 is amended as follows:

In the case of a porous anode, soak in can be prevented using a variety of methods which include, for example, (1) applying a nonporous layer to the surface of the porous anode and, after patterning the mask, removing the nonporous layer in the negative areas of the mask to expose the anode; (2) sintering a partly-compacted powder of anode material in a mold to create a sintered anode with an outer non-porous layer, patterning the mask from a masking material that is applied over the sintered material, and immersing the structure in an etchant

that attacks the metal of the anode, such that the outer non-porous layer of sintered anode material is dissolved (in the unmasked regions); (3) melting the surface of the anode (e.g., by flame, or contact with a hot surface), then patterning the mask and removing the melted surface material to expose the porous anode material in unmasked regions; and (4) temporarily filling the surface pores with a material, e.g., metal electrodeposited onto the porous surface, then patterning the mask and removing the temporary filler material to expose the porous anode material in unmasked regions]; and by applying a nonporous barrier layer between the mask and the anode].

The paragraph starting at page 15, line 10 is amended as follows:

A variety of methods can be used to pattern the electroplating article. Referring to Figs. 4a-4e, an example of a method for forming an electroplating article is shown. The method includes forming a micromold 140 by coating (e.g., by spinning) a layer of resist 142 (e.g., photoresist commercially available under the trade designation SU-8 5 from MicroChem Corp.) onto a substrate 144 (e.g., a silicon wafer) (Fig. 4a). Preferably the layer of photoresist has a thickness a few microns greater than that of the desired thickness of the final mask. The photoresist can be patterned using a photomask and[, in the case of photopatternable resist compositions,] a light source (e.g., a UV light source). A positive feature of the resist corresponds to a negative feature of the mask. Optionally, the micromold can be made from a non-stick material such as[, e.g.,] polytetrafluoroethylene or polypropylene, and can include a pattern formed, e.g., by reactive ion etching or excimer ablation, or micromolded from a master mold according to processes similar to processes used in the fabrication of compact disks.

The paragraph starting at page 15, line 23 is amended as follows:

The micromold surface including the photoresist and the substrate can be passivated by allowing the micromold to be exposed to vapors of, e.g., (tridecafluoro-1,1,2,2,-tetrahydrooctyl)-1-trichlorosilane (commercially available from United Chemical Technologies). A liquid masking composition 146 is then poured over the raised pattern defined by the patterned photoresist (Fig. 4b). Support 148 is then pressed against micromold 140 (Fig. 4c). Uniform pressure is applied such that liquid masking composition [148] 146 is forced out of the area 150 located between the raised portions (i.e., positive features) of the resist pattern and the surface of support 148. Preferably, liquid masking composition 146 is

completely squeezed out of the areas 150 corresponding to the positive features of resist 142. The entire assembly 152 remains in this mating relationship until the liquid masking composition has cured. For a heat-curable masking composition, the assembly can be transferred to an oven to cure.

The paragraph starting at page 16, line 4 is amended as follows:

[After cure, excess mask material 154 surrounding support 148 is removed.] In the case of a mask that has been cured in the oven, the assembly is quickly disassembled to minimize differential thermal contraction between support and the mold. The support and cured mask 156 is pulled away from mold 140 such that cured mask 156 detaches from micromold 140, yet remains adhered to support 148 (Fig. 4d). Mask 156 exhibits a pattern inverse to that of micromold 140. Micromold 140 can be reused. After cure, before or after detachment of the mask and mold, excess mask material 154 surrounding support 148 is removed as illustrated in Fig. 4e. If necessary, micromold 140 can be cleaned to remove mask residue. One example of a useful silicone cleaning composition is a silicone stripper, e.g., Amtex CCR (commercially available from Amtex Chemical Corp.).

The paragraph starting at page 16, line 13 is amended as follows:

Any residual layer of masking composition remaining in negative features 158 of mask 156 (Fig. 4d) can be removed using dry etching (e.g., RIE with a mixture of O₂ and CF₄ gas), which may also reduce the thickness of the positive features of the mask. The result of such removal is depicted in Fig. 4e. Uniform etching extending to the edge of the support can be accomplished by surrounding the support with a “dummy” substrate preferably of similar composition, such that non-uniformities due to edge effects are out of the area of interest.

The paragraph starting at page 16, line 24 is amended as follows:

Another method for forming an electroplating article is shown in Figs. 5a-5e. The method includes patterning a photoresist 142 onto a support 148 (i.e., the porous medium or the prepared anode) to the approximate thickness desired for the final mask (Fig. 5a). The areas of support 148 occupied by resist 142 correspond to negative features of the mask through which metal can be deposited. When patterning a porous medium that includes a barrier, the porous medium can be etched to remove the barrier layer from those areas of the porous medium that are not covered by resist. The method further includes applying a liquid masking composition 146 to support 148 (Fig. 5b), and optionally vacuum degassing the

masking composition. A flat, smooth, non-stick (e.g., PTFE) sheet 160 is then pressed against resist 142, and liquid masking composition 146 parallel to support 148 (Fig. 5c), and pressure is applied to squeeze the liquid masking composition 146 out from between resist 142 and sheet 160. Masking composition 146 is then cured, sheet 160 is removed, and residual masking composition overlaying the resist is removed (Fig. 5d), e.g., by etching (e.g., reactive ionization etching using a mixture of O₂ and CF₄ gas). Resist 142 is then removed to expose areas of the support previously occupied by the resist (Fig. 5e). When patterning a porous medium, mask material that has seeped into the negative features of the mask from neighboring positive features can be removed by etching both mask and porous medium to the required depth. If pores of the porous medium have been filled or are non-existent, the pores can be established or re-established.

The paragraph starting at page 17, line 13 is amended as follows:

Referring to Figs. 6a-6d, another method for forming an electroplating article includes applying (e.g., by spinning on) a layer of photopatternable liquid masking composition 146, e.g., RMS-O33 (commercially available from Gelest) in combination with a photoinitiator (e.g., 2,2-dimethoxy-2-phenyl acetophenone (commercially available from Polysciences, Inc.)), to support 148 (Fig. 6a). Liquid masking composition 146 can be covered with a thin, oxygen-impermeable film (e.g., Mylar) to protect the composition from contact with oxygen. Masking composition 146 is then exposed to patterned light (e.g., UV light transmitted through a photomask 162) to selectively cure the mask composition (Fig. 6b). The film is removed (Fig. 6c) and the photopatternable masking composition is developed (e.g., by dissolving with xylene) removing uncured masking composition 146 (Fig. 6d). If a nonporous barrier layer exists, it is removed (e.g., by dry etching) from the negative features of mask 156. Pores are established if necessary. For those photopatternable masking compositions that are negative working the porous medium can be completely saturated with masking composition until there is a surface layer of masking composition having the desired thickness. After photopatterning, the unexposed masking composition material (including that in the pores) is dissolved in the developer.

The paragraph starting at page 18, line 1 is amended as follows:

Referring to Figs. 7a-7f, another method for making an electroplating article is shown. The method includes applying a liquid masking composition 146 (or a solid mask material) to

support 148 (Fig. 7a); curing liquid masking composition to form an unpatterned solidified mask 156; coating unpatterned mask 156 with either a thick resist 164 or a thin resist disposed on a thin metal layer (not shown) (Fig. 7b); patterning resist 164 and, in the case of a metal layer, using the patterned resist to pattern the metal layer (e.g., by etching or lift-off) (Figs. 7c and 7d); selectively removing (e.g., by wet etch, dry etch, or ion mill) portions of unpatterned mask 156 to form a patterned mask 156 using thick resist 164 (and metal layer if present) as a mask (Fig. 7e); and in the case where the substrate is a porous medium, preferably removing the top layer of the porous medium to open pores; and removing, e.g., by stripping, the remaining resist 16a (and metal layer if used) (Fig. 7f).

The paragraph starting at page 18, line 11 is amended as follows:

Referring to Figs. 8a-8c, a method for forming an electroplating article is shown which includes: applying a liquid masking composition 146 (or a solid mask material) to support 148 to the desired, thickness; curing (if liquid) the masking composition to form solidified unpatterned mask 156 (Fig. 8a); applying a photomask 162 over the mask 156 (Fig. 8b) where the photomask has light apertures 166 and light barriers 168; exposing solid mask 156 to patterned ultraviolet light through the photomask 162 (Fig. 8c), the UV light having an [of] intensity and wavelength suitable for ablating the mask and support material, e.g., a LTV excimer laser beam; ablating mask 156 until support 148 is exposed (Fig. 8c); and, when patterning a porous medium, ablating barrier layer 170, [(if present)] (Fig. 8d) and, if necessary, the top layer of the porous medium to open pores; and removing the photomask to form the electroplating article 172 (Fig. 8e).

The paragraph starting at page 18, line 26 is amended as follows:

Another example of such a method includes: creating a relief pattern on the support by etching of the support, or by applying a durable photoresist, e.g., SU-8 of desired configuration; coating a flat, smooth sheet with a thin, uniform layer of liquid masking composition; stamping the support/resist against the coated sheet ([i.e.] e.g., like a stamp and inkpad) to quickly mate those portions of the liquid composition to the positive features of the support/resist by [and unmate the support/resist and the masking composition] unmating them from the smooth sheet (preferably the support and the sheet are kept parallel); and curing the liquid masking composition.

The paragraph starting at page 19, line 1 is amended as follows:

Referring to Figs. 9a-9c, a method for forming an electroplating article is shown in which a surface layer of porous medium 148 is saturated with a liquid masking composition to the thickness of the desired mask. Liquid masking composition is solidified producing a matrix 174 of solid mask 156 and porous medium 148. Matrix 174 is then patterned, e.g., by etching or ablating selected areas of the matrix to a depth at least equal to the depth of the matrix "layer", to form electroplating article 176. Alternately, the method can include saturating the entire porous medium with liquid masking composition, pattern curing the liquid masking composition, and removing the uncured masking composition.

The paragraph starting at page 19, line 20 is amended as follows:

In general, select embodiments of the invention features electroplating methods that include contacting a substrate to be plated with an electroplating article [of the invention]; selectively electroplating a first metal, e.g., a support or sacrificial metal; and electroplating a second metal, e.g., a structural metal. The step of electroplating a second metal can include selectively electroplating the second metal using an electroplating article [of the present invention] or blanket depositing the second metal. The electroplating method can be used to plate a single layer of metal or the method can be repeated such that additional metal is plated onto previously plated metal layers producing a multi-layered structure. After a predetermined number of layer(s) have been plated, at least a portion of the support metal can be removed, e.g., by etching. The structural metal that remains defines a microscopic or mesoscopic device.

The paragraph starting at page 20, line 1 is amended as follows:

The method can also employ two electroplating articles to plate a single layer of one metal. Referring to Figs. 10a-10c, a first metal is plated in a first pattern 230 (Fig. 10a), the same metal is then plated in second pattern 232 (Fig. 10b), to form plated metal layer 234 (Fig. 10c). Second pattern 232 may overlap first pattern 230.

The paragraph starting at page 20, line 5 is amended as follows:

One example of an electroplating method of an embodiment of the invention is shown in Figs. 11a-11m. The method includes contacting a substrate to be plated 2 (Fig. 11a) with first article 4a, which includes mask 6 and support 8 (Fig. 11b), in the presence of a first metal ion source (i.e., electrolyte and anode 10);[,] depositing a first metal 12 (Figs. 11b and 11c),

e.g., a sacrificial metal;[,] contacting substrate 2 with a second article 14a, which includes mask 16 and a support 18, depositing a second metal 20, e.g., a structural metal, in the presence of a second metal ion source (i.e., electrolyte and anode 22) (Fig. 11d);[,] optionally planarizing the layer;[,] and repeating this method using differently patterned electroplating articles [4a,] 4b, 4c, [14a,] 14b, 14c (Figs. 11e-11k) to produce multi-layered structure 24 (Fig. 11l), which, after etching all of sacrificial metal 12, becomes element 26 (Fig. 11m). The second article can include a mask that has oversized positive features such that the surface area of one or more positive features of the mask extends beyond the corresponding surface area of the first plated metal.

The paragraph starting at page 20, line 21 is amended as follows:

Another electroplating method is depicted in Figs. 12a-12c. The electroplating method includes: contacting a substrate to be plated 2 with an electroplating article (not shown); selectively depositing a first metal 12 (i.e., either the structural or the support metal) (Fig. 12a); blanket depositing a second metal 20 (Fig. [12a] 12b), and mechanically planarizing the deposited layer to achieve a flat, smooth layer 28 of precise thickness (Fig. [12b] 12c). The planarized surface can be rinsed to remove abrasive particles present on the surface. Preferably the support metal is selectively plated and the structural metal is blanket deposited.

The paragraph starting at page 20, line 29 is amended as follows:

Examples of useful planarization methods include mechanical (e.g., diamond lapping and silicon carbide lapping), chemical-mechanical, and non-mechanical (e.g., electrical discharge machining), planarization processes. Diamond lapping is a particularly preferred planarization process. Diamond lapping can be performed using a single grade of diamond abrasive, e.g., about 1-6 micron, or diamond abrasives of various grades. Lapping with different grades of abrasive can be performed using separate lapping plates, or in different regions of a single plate. For example, a coarse diamond abrasive can be applied to the outer region of a spinning circular lapping plate, and a fine diamond abrasive can be applied to the inner region. A removable circular wall can be provided between the inner and outer regions to increase segregation. The layer to be planarized first contacts the outer region of the plate, is then optionally rinsed to remove coarse abrasive, and then is moved to the inner region of the plate. The planarized surface can then be rinsed using a solution, e.g., water-based or

electrolyte-based solution, to remove both abrasive and abraded particles from the planarized layer. The abrasive slurry preferably is easily removable, e.g., water-soluble. Layer thickness, planarity and smoothness can be monitored, e.g., using an optical encoder, wear resistant stops, and by mating the layer under a known pressure with a precision flat metal plate and measuring the resistance across the plate-layer junction. Thickness of the plated metal can also be measured by, for example, contacting the plated metal with a mask having a pattern that is complementary to the plated metal pattern and measuring the displacement.

The paragraph starting at page 21, line 27 is amended as follows:

The substrate to be plated can include a conductive surface or a nonconductive surface provided with a conductive layer. The substrate to be plated can be planar or nonplanar. The substrate to be plated can also be a previously electroplated or deposited metal or a layer that includes at least one metal[(s)].

The paragraph starting at page 22, line 1 is amended as follows:

The electroplating method can be performed, e.g., on an integrated circuit. One example of an electroplating method performed on an integrated circuit is shown in Figs. 13a-13i. To permit electrical contact during plating, the aluminum pads can be connected to conductors that terminate at distant contact pads, which can be temporarily tied together by a bus. Referring to Figs. 13a-13i, the electroplating method of this embodiment includes: spin coating a layer of polyimide 34 onto thin copper disk 36; adhering copper disk 36 to bottom surface of silicon wafer 38 with the polyimide coated surface of the copper disk contacting the bottom surface of the wafer (Fig. 13b), which includes aluminum pad 40, narrow conductor 42, contact pad 41, and passivation layer 44 (Figs. 13a and 13b); partially sawing through wafer 38 to assist separation of the die after processing; spin coating photosensitive polyimide 35 on the top surface of wafer 38 to protect aluminum pads 40 and 41 during subsequent etching and to fill saw line 46; patterning polyimide to expose pads 40 to be plated [40] and pads 41 for electrical contact [41] (Fig. 13c); degreasing wafer; immersing the structure in zincate plating solution; applying photoresist and patterning to create a bus; joining contact pads 41 by sputtering of copper to form a bus 48 (Fig. 13d) that is in contact with pads 41 for the electroplating method; patterning resist 35 over bus 48 to prevent nickel from depositing on bus 48; plating enough nickel 50 (Fig. 13e) on aluminum pad 40 to allow planarization; removing the resist 35; making electrical contact with the plated metal; sputtering a planar

base 51 and plating a sufficient amount of copper 52 over the entire wafer surface to allow planarization; planarizing surface to expose nickel 50 (Fig. 13g); electroplating the layers of the microstructure (Fig. 13h); etching copper 51 and 52 including bus 48 and copper disk 36; and stripping polyimide 34 thereby defining microstructure device 54 attached to wafer 38 (i.e., the integrated circuit) (Fig. 13i).

The paragraph starting at page 23, line 3 is amended as follows:

Uniformity of the plated metal layer can be improved by controlling current density and adjusting current density on a feature-by-feature basis by controlling the local thickness, and optionally the local porosity, of the support of the electroplating article. Uniform plating can also be achieved by [use as support] using an insoluble anode as a support, where the insoluble anode has [having] a thin layer of a soluble coating located thereon that has [having] a thickness calculated to provide the desired thickness of plated metal on the substrate. Once the finite amount of ions in the volume of electrolyte within the area defined by the mask (including ions created from any soluble coating that was initially part of the anode) are consumed plating ceases and [,] the coating and the substrate are plated[, plating ceases]. As long as the initial coating on the insoluble anode is uniform in thickness, the plated metal will be uniform in thickness.

The paragraph starting at page 23, line 12 is amended as follows:

Hydrogen bubble formation can also be minimized by employing a low current density to increase current efficiency; decreasing temperature and/or pressurizing the electrolyte in bulk to increase the solubility of hydrogen in the electrolyte; employing a mask material that is impermeable to the electrolyte but gas permeable (e.g., a hydrophobic microporous material); performing the electroplating method under vacuum so that gas bubbles are pulled out of the mask features; employing antipitting agents (e.g., SNAP for nickel sulfamate electrolytes) to minimize the formation of pits by reducing the attachment of the gas bubbles to the substrate; increasing the masking pressure, which can locally increase electrolyte pressure due to reduced microvolume, which will establish large pressures on the electrolyte in localized areas keeping hydrogen in solution; and incorporating hydrogen gettering agent into the mask material (e.g., by mixing a fine powder into the liquid masking composition).

The paragraph starting at page 23, line 24 is amended as follows:

Examples of useful etching compositions for selectively stripping copper from nickel structures include: solutions of ammonium hydroxide and copper sulfate, solutions of ammonium hydroxide and sodium chlorite, with ammonium hydroxide-copper sulfate solution being preferred for etching structures attached to CMOS devices, and Enstripe C38 commercially available from Enthone OMI. Etching can also be performed in the presence of vibrations, e.g., ultrasound applied to the [electrolyte] etchant or the substrate that was [being] plated, pressurized jets of etchant contacting the metal to be etched, and surfactant. Flash present on the structural metal, e.g., in the form of thin projections extending from the surface of the structural metal, can be removed, e.g., by acid etching or electropolishing.

The paragraph starting at page 24, line 3 is amended as follows:

The electroplating [methodes] methods can be used to manufacture elements having complex microstructure and close tolerances between parts. One example of a method for manufacturing elements having parts that fit with close tolerances, e.g., gaps between the parts are between about 1-5 um, involves electroplating the parts of the device in an unassembled, preferably pre-aligned, state. Once manufactured, the individual parts can be moved into operational relation with each other. Referring to Figs. 14a-14e, a method of manufacturing device 188 including gear 190 and shaft 192 having retaining clips 200 includes the electroplating methods disclosed above. Assembly fixture 194 is plated in a pre-aligned location with gear 190 (Fig. 14a). Chuck 196 (e.g., electromagnetic or vacuum) secures the assembly fixture pieces 194 as support material 198 is etched (Fig. 14b). During etching gear 190 may fall into contact with shaft 192. Chuck 196 is then lowered, causing assembly fixture 194 to press gear 190 over retaining clips 200 on shaft 192 and into final position, as shown in Fig. 14c. Chuck 196 is then raised removing assembly fixture 194 from the completed device 188, as shown in Figs. [14d-e] 14d and 14e.

The paragraph starting at page 24, line 17 is amended as follows:

The electroplating method can also be used to manufacture elements in which at least a portion of the support metal (i.e. normally sacrificial metal) is enclosed within the structural material such that the enclosed [structural] sacrificial metal is not etched away during the removal process and thus becomes part of the structure of the element. Referring to Figs. 15a and 15b, a cross section of a plated element 236 (Fig. 15b) is shown in which support metal

238 remains encapsulated within structural metal 240 after the portion of support metal 238[,] that is accessible by etchant (Fig. 15a)[,] is removed.

The paragraph starting at page 24, line 23 is amended as follows:

The electroplating processes can also be used to manufacture tooling for molding (e.g., injection molding, metal injection molding, reaction injection molding, thermoforming, blow molding, and die casting). Mold inserts can be manufactured by orienting [the two] mold inserts so that the ejection axis of the part is parallel to the stacking axis of the layers and the parting surface of the part to be molded is the last layer deposited. The electroplating methods can be used to form parts (i.e. elements) that include undercuts as shown in Fig. 16a, to form parts without draft as shown in Fig. 16b, and to form molds without undercuts and with draft by depositing layers of structural material where each subsequently plated layer of structural metal lies entirely within the boundary of the previously deposited layer (e.g., layers 801-805) of structural metal, as shown in Figs. 16c. The object produced by the mold of Fig. 16c is shown in Fig. 16[and]d. The mold of 16c can [,] optionally be produced without the use of a support (i.e. sacrificial) material. Referring to Fig. 16c, layer [800] 801 is deposited before layer [801] 802, and so on.

The paragraph starting at page 25, line 5 is amended as follows:

The electroplating method can be performed in a variety of electroplating apparatus. One particularly useful apparatus for carrying out an electroplating method is shown in the side view of Fig. 17. Apparatus 56 includes two baths 58, 60 (e.g., a nickel plating bath and a copper plating bath), and an inspection station 62. Each bath 58, 60 is constructed to be capable of electroplating a different metal. Each bath 58, 60 includes an electrolyte, an anode 59, 61, and an electroplating article 4, 14. As shown, apparatus 56 accommodates a single substrate to be plated 2. The apparatus can be constructed to accommodate multiple substrates to be plated and multiple electroplating articles. Each article 4, 14 includes at least one patterned conformable mask 6,16 and is capable of depositing a pattern of metal.

The paragraph starting at page 25, line 15 is amended as follows:

The mechanical and electrochemical control of the electroplating [method] apparatus can be controlled by computers to implement the electroplating method. Substrate to be plated 2 is transported by precision motion stages 64x, 64y, 64z, equipped with DC servo motors, stepper motors or combinations thereof, and precision encoders, between plating

baths 58, 60 and rinsing station 66. Substrate 2 suspended on chuck 68 enters first bath 58, positions itself over mask 6, contacts mask 6, and undergoes plating. After a predetermined thickness of metal has been plated onto substrate 2, substrate 2 is removed from bath 58, rinsed and transferred to second plating bath 60 where it contacts a second mask 16, undergoes plating to a predetermined thickness (preferably the same thickness of the first deposited metal), is rinsed, and is returned to first bath 58. Inspection station 62, including a high-resolution video microscope system with PC frame grabber, can be used in conjunction with control software to automatically record images of the deposited layers to a hard disk. Preferably apparatus 56 is enclosed in a sealed chamber and equipped with a vacuum system to degas the mask.

The paragraph starting at page 26, line 28 is amended as follows:

The thickness of the plated metal and plated metal layer can be controlled, e.g., by measuring the deposition rates of the metals and plating for a predetermined period; monitoring the integrated current, with adjustments for plating efficiency, normalizing for calculated mask area and calculating plating thickness; and through closed loop thickness control. The closed loop system includes [inputing] inputting an estimate, based upon measured metal plating rates, into the software that controls the electroplating method; plating a first metal to less than the desired thickness, pressing the substrate against a second electroplating article, such that the mask of the electroplating article contacts the first plated metal; forcing the substrate to move away from the support by an amount equal to the thickness of the plated layer; reading the thickness of the first plated metal using a high resolution (e.g., 0.1 um) encoder, linked to the substrate chuck; [inputing] inputting this data into the software to update the stored rate value for the first metal; plating the remaining thickness of the first metal layer. This process and its complement for measuring the plating thickness of the second plated metal can be repeated every few layers as a calibration.

The paragraph starting at page 27, line 25 is amended as follows:

Referring to Fig. 19, a portion of another electroplating apparatus 66 that includes bath 68 containing ions of a first metal, e.g., a nickel plating bath, bath 70 containing ions of a second metal, e.g., a copper plating bath, and multiple electroplating articles 72a-f and 74a-e[f], is shown. Each substrate to be plated [2 (labeled) (2a-2e)] enters the apparatus 66 at the left end 76 of bath 68, contacts article [74a] 72a, becomes plated with a first metal in the

pattern of the mask of article [74a] 72a, transfers to bath 70 after rinse (not shown), contacts article [70a] 74a, becomes plated with a second metal in the pattern of the mask on article [70a] 74a, transfers to article [74b] 72b after rinse (not shown), in bath 68 and so on. As depicted, substrate 2a has received deposits of the first metal and the second metal for the first three layers of the microstructure and the first metal portion of the fourth layer. Substrate 2b is one layer behind substrate 2a;[,] substrate 2c is two layers behind [wafer] substrate 2a, etc.

The paragraph starting at page 28, line 5 is amended as follows:

For elements (e.g., devices) that require dozens or hundreds of deposited layers, the electroplating system can be arranged in an annular design in which the electroplating articles are arranged in rings and in which the individual electroplating articles are replaced after having contacted each of the substrates to be plated. One example of an apparatus for [mass producing] mass-producing electroplated structures is shown in Fig. 20. Apparatus 78 is designed to process 24 eight-inch diameter substrates 2. Apparatus 78 is concentric in design and includes an [two] outer ring[s] 80, and a middle ring 82 and a central disk [84] 85. Outer ring 80 includes electrolyte bath 84 and electroplating articles (not shown) for selectively plating a first metal. [Inner] Middle ring 82 includes an electrolyte bath 86 for blanket-plating a second metal. As opposed to blanket plating, middle [Inner] ring 82 can include electroplating articles for selectively plating the second metal. Rotating lapping plate 85 (if required), for planarizing the plated metal layers, is located at the center of apparatus 78. All processes (first metal selective plating, second metal blanket or selective plating and, optionally, planarization) occur during a single cycle, but on different substrates 2. At the end of the cycle, the substrates undergoing plating move in the pattern shown, in part, by arrows. Eight layers have been deposited after having completed all of the cycles in the system and arriving back at the starting point. Prior to the first substrate arriving back at the first plating article, the first plating article can be replaced by a new plating article. Likewise after the other plating articles have contacted each of the substrates they can be replaced, and substrates 2 can continue around apparatus 78, receiving as many layers as are required for the device being made. Rinsing stations are not shown but can be located in the spaces between the plating articles. It is anticipated that such [Such] an apparatus would permit the simultaneous manufacture of about 2.5 million devices, each 500 microns square by 200 microns tall, in [a 8 hour] an 8-hour period.

The paragraph starting at page 28, line 28 is amended as follows:

The electroplating apparatus can also include a single bath containing ions of at least two metals (e.g., a Watts bath with added copper sulphate). A method for selectively depositing two metals from a common plating bath of their ions is described in H. Yahalom and O. Zadok, "Formation of Compositionally Modulated Alloys by Electrodeposition," J. Material Sci., Vol. 22, p. 494 (1987). The plating bath includes at least two electroplating articles, each of which is dedicated to plating one of the metals. The articles can include a single mask pattern or multiple mask patterns in a [side by side] side-by-side arrangement on the surface of the support. In the case of an article having multiple mask patterns, the substrate can contact the different mask patterns in a predetermined sequence, alternating with the mask pattern(s) on the second article, to build a three dimensional structure. Referring to Fig. 21, an electroplating apparatus 88 that includes a single bath 90 containing ions of two metals, e.g., nickel and copper ions, articles for plating the first metal 92, articles for plating the second metal 94, and substrates 2a-e, is shown.

The paragraph starting at page 29, line 11 is amended as follows:

Each substrate 2a-2e enters apparatus 88 at the left end 96 of bath 90, contacts electroplating article 92a becomes plated with the first metal in the pattern of the mask of electroplating article 92a, transfers to and contacts article 94a, becomes plated with the second metal in the pattern of the mask on electroplating article 94a, transfers to electroplating article 92b, and so on. As depicted, substrate 2a has received deposits of the first metal and the second metal for the first three layers of the microstructure and the first metal portion of the fourth layer. Substrate 2b is one layer behind substrate 2a, substrate 2c is two layers behind substrate 2a, and so on.

The paragraph starting at page 29, line 19 is amended as follows:

A variety of methods can be used to improve the copper deposition rate in a common bath electroplating system including, e.g., pulsing the plating current, increasing temperature (e.g., laser enhanced plating), pumping electrolyte through the support of the electroplating article, ultrasonic vibration, and increasing the copper content in the vicinity of the copper disk. One method for locally increasing the concentration of copper includes galvanostatic dissolution of the copper anode while plating onto a dummy substrate. By applying a current pulse at a density of, e.g., about 20-50 mA/cm², both nickel and copper are deposited onto the

dummy substrate until sufficient copper to form a layer (about 1-2um thick) is generated in the electrolyte located between the anode and the substrate. At this point the dummy substrate is substituted with the real substrate and the anode is replaced with a nickel anode. Copper is then deposited [potentionstatically] potentiostatically.

The paragraph starting at page 30, line 1 is amended as follows:

Another method for locally increasing the concentration of copper includes employing [a] an electroplating article holder 98 as shown in Fig. 22. The volume of electroplating article holder 98 contains copper rich electrolyte and is defined by side walls 100 of a cylinder, a porous support 102 having a conformable mask 104, and anode 106 (e.g., an insoluble platinized titanium anode). Electroplating article holder 98 includes inlet and outlet ports for transferring electrolyte (not shown). This electroplating article holder can be immersed within a [nickel plating] nickel-plating bath, optionally separated by a barrier through which the substrate can intermittently pass.

The paragraph starting at page 30, line 9 is amended as follows:

In general when there is a risk of spontaneous deposition onto a substrate while not in contact with an electroplating article, the substrate preferably is biased at a more positive potential than that at which copper reduction would occur until the substrate has contacted the [copper electroplating] copper-electroplating article and current has been applied. Similarly, when current is removed, the substrate preferably is again biased until the substrate is removed from the electrolyte, or applied to another article and current is again applied.

The paragraph starting at page 30, line 15 is amended as follows:

Another electroplating apparatus is shown in Fig. 23. Apparatus 260 includes baths 262, 264 (e.g., a nickel plating bath and a copper plating bath), by an inspection station 266, and lapping station 268. Each bath 262, 264 is constructed to be capable of electroplating a different metal. Each bath 262, 264 includes an electrolyte and an anode 270, 272. Bath 264 also includes an electroplating article 274 for selectively depositing a first metal. Bath 262 is used for blanket depositing a second metal. Bath 262 includes a mask 276 for insulating the sides of the structure (i.e. including the element) being fabricated on substrate 2 to prevent metal from plating on the sides of either [one] the substrate or the structure. Referring to Fig. 24, a portion of electroplating apparatus 260 in which substrate 2 is positioned within

electroplating bath 262 and is insulated, in part, by mask 276 is shown. Substrate 2 includes a selectively deposited layer 278 and a blanket deposited layer 280.

The paragraph starting at page 30, line 26 is amended as follows:

Referring to Fig. 25, an example of an electroplating apparatus that includes an electroplating article that includes a porous membrane is shown. Electroplating article 108, which is in contact with substrate to be plated 2, includes a relatively more rigid porous medium 110 having a relatively more coarse porosity, and relatively [more thin] thinner, flexible porous membrane 112 having a relatively more fine porosity, and patterned mask 114 adhered to membrane 112. Patterned mask 114 is in contact with substrate 2 and anode 116 is disposed beyond porous medium 110. A metal deposit 118 is formed in the opening (i.e., within a negative feature) defined by mask 114.

The paragraph starting at page 31, line 3 is amended as follows:

Referring to Fig. 26, another example of an electroplating apparatus 120 that employs a porous membrane 112 is shown. Porous membrane 112 is mounted as a [on] drumhead on drum frame 122 in a way that allows for handing and processing, [maintains] maintenance of position of the membrane 112 with respect to the substrate, and allows pressure to be exerted on porous membrane 112 through rigid porous medium 110 contacting porous membrane 112. Porous membrane 112 is clamped between concentric O-rings 124, and pulled taut over a rigid porous medium, or, as shown, a cylindrical, hollow "barrel" 126 by tightening screws 128. If a barrel is used, rigid porous medium 110 is placed within barrel 126 so as to make contact with one side of membrane 112. Plating substrate 2 contacts the other side of porous membrane 112. An intermediate compliant material (not shown) e.g., an open pore foam, may be disposed between porous membrane 112 and rigid porous medium 110 to provide a more uniform contact pressure between the mask and plating substrate 2.

The paragraph starting at page 31, line 17 is amended as follows:

Various embodiments of the [The] invention also feature[s] a method for generating [a] mask patterns of very thin cross section for a three dimensional structure and a method for automated electroplating that includes contacting electroplating articles having the generated mask patterns in a predetermined sequence to form the three dimensional structure.

The paragraph starting at page 31, line 21 is amended as follows:

One such embodiment [The method] employs an automatic mask minimization algorithm for optimizing the number of masks for a given geometry. Application of the method to a valve like device 602, shown in Fig. 27, can be described with reference to perforated lines A-D which indicate cross sections of the device 602. [Cross sections] Cross-sections B and C are identical and cross sections A and D are identical. A single mask can be used for cross sections B and C and another mask can be used for cross sections A and D. The algorithm compares the newly calculated cross sections for use with a given metal with the previously calculated cross sections for the same device or possibly those used to make [the] other devices [and same metal]. A new mask is generated if the difference between the two cross sections exceeds some predetermined (e.g., user specified) tolerance. This allows the number of masks to be minimized, allowing a greater number of layers to be produced from fewer electroplating articles. The program also generates an apparatus control file which directs the software that controls the electroplating apparatus such that masks are selected in a predetermined sequence corresponding to mask location within the electroplating apparatus and the layer being plated. The system can also export a layout file representing the first cross section of the part to be fabricated, allowing pad design for CMOS interfacing using a standard layout editor. The system can also display calculated cross sections to the user to allow error checking.

The paragraph starting at page 32, line 8 is amended as follows:

Fig. 28 is a functional block diagram of an exemplary computing system for calculation of cross sections of a three dimensional structure in accordance with an embodiment of the present invention. As shown in Fig.28, system 610 may include a processor 612, a memory 614 (e.g., a random access memory (RAM), and a program memory (for example, a writable read-only memory (ROM) such as a flash ROM)), input devices 616, and output devices 618. Processor 612 includes a central processing unit (CPU) that forms part of a [general purpose] general-purpose computer, such as a PC, Macintosh, or workstation. Memory 614 stores program code for execution by processor 612 including operating system code and application program code, and generally represents a magnetic hard drive or other storage device in combination with a random access memory accessed by processor 612. As one example, memory 614 could be realized in part by a storage drive contacting removable storage media carrying the application program code. Input devices

616 include input media for entry of user input, such as a keyboard, mouse, and the like. Output devices 618 include display devices including a view screen that provides graphic output, e.g., a CRT or flat panel monitor, a printer (e.g., a desk top printer, an inkjet printer, a laser printer, a photoplotter, and the like), the electroplating apparatus [of the present invention], a linotronic printer and the like.

The paragraph starting at page 32, line 25 is amended as follows:

Fig. 29 is a flow diagram illustrating a method for generating mask geometries and machine control parameters for fabrication of a three dimensional structure. When the user starts the application program, as indicated by reference numeral 620, processor 612 receives and processes input corresponding to the three dimensional geometry of a structure to be cross sectioned from input devices 616 as indicated by block 622. Processor 612 determines the extents in layer plane of the entire geometry of the [three dimensional] three-dimensional structure as indicated by block 623. Processor 612 sets M, the number of layers (including one or more cross sections), equal to 1 and generates cross sections for the Mth layer, as indicated by block 624. Processor 612 reads inputs relevant to each mask geometry including, e.g., scaling of the three dimensional geometry, layer thickness, mask dimensions, number of copies and spacing, and tolerance for mask minimization, as indicated by block 625. Processor 612 creates the geometry of mask corresponding to the Mth layer, as indicated by block [616] 626, writes the geometry of the cross section(s) to a mask pattern file, indicated by blocks 628 and 630, and writes mask identification numbers for the Mth layer to a machine control file, as indicated by blocks 628 and 632. Memory 614 stores mask pattern in the mask pattern file, as indicated at block 630. Memory 614 stores location information in machine control file, as indicated at block 632. Processor 612 queries if additional [cross sections] layers are needed to complete the geometry of the [three dimensional] three-dimensional structure, as indicated at block 634.

The paragraph starting at page 33, line 25 is amended as follows:

If so, processor 612 increments N by 1 and compares the geometry of mask for Mth layer with that of mask for M-Nth layer, as indicated at block 642. If processor 612 calculates that the geometry of the Mth layer has been compared to the geometry of each previous mask and no geometry matches have occurred (i.e. a "no" answer to the inquiry of 654), then processor 612 creates a geometry of the mask for the Mth layer, as indicated at block 656.

Processor 612 then writes the geometry for the Mth layer to the mask pattern file (as indicated by block 658), sends an output to the mask pattern file, as indicated by block 660, and writes mask identification number for the Mth layer to the machine control file (as indicated by blocks 650 and 652).

The paragraph starting at page 34, line 3 is amended as follows:

Processor 612 queries whether additional [cross sections] layers are required to be made of the three dimensional object (as indicated by block 634).

The paragraph starting at page 34, line 7 is amended as follows:

Fig. 30 is a flow diagram illustrating a method for electroplating a metal onto a substrate using patterned masks that represent a cross [section] sectional slice of a three dimensional object. When the user starts the application program, as indicated by reference numeral 720, processor 612 signals [to] the electroplating apparatus to perform machine initialization and sets M, the number of layers plated equal to zero, as indicated at block 722. Processor 612 increments M by 1 (as indicated by block 724), sets P (i.e., the number of different metals to be plated) equal to 1 and optionally biases the substrate to prevent spontaneous deposition of the metal (as indicated by block 726). Processor 612 reads machine control file (indicated by block 730) to [determine which] obtain control information about the layer that is to be plated, and reads mask location file (indicated by block 732) to [calculate] obtain information about the location of the mask pattern to be plated [(indicated by block 728)]. Processor 612 directs the electroplating apparatus to align the substrate to be plated with the mask for material P of layer M and to contact the substrate to the mask (indicated by block 728). Processor 612 optionally measures layer thickness, if necessary, as indicated by block 734. Processor 612 receives input that the substrate is in contact with the mask and turns off substrate bias (if turned on), as indicated by block 736. Processor 612 instructs apparatus to deposit material P for layer M, as indicated by block 738. Processor 612 receives input that the cross-section [layer] has been deposited and applies a bias to the structure, if required, as indicated by block 740. Processor 612 instructs apparatus to remove the substrate from contact with the mask (as indicated at block [740] 742), and to planarize layer M to predetermined thickness (if necessary), as indicated at block 744. Processor queries whether P is [greater] less than the number of metals of layer M, as indicated by block 746.

The paragraph starting at page 34, line 29 is amended as follows:

If so, processor 612 increments P by 1 (as indicated by block 748), and drives the electroplating apparatus to align the substrate with a mask corresponding to the new value for P (i.e., [Pi +1]) the P metal of layer M), as indicated by block 728. Processor 612 drives electroplating apparatus to contact the substrate with the mask (as indicated by block 748), and the above process is repeated until P is equal to the number of metals on layer M.

The paragraph starting at page 35, line 3 is amended as follows:

Turning back to block 746, if [If] P is not less than the number of materials on layer M, processor 612 queries whether M is the final layer (as indicated by block 750).

The paragraph starting at page 35, line 8 is amended as follows:

The data processes and control processes of various embodiments of the invention can be implemented in digital electronic circuitry, or in computer hardware, firmware, software, or in combinations thereof. The data processes and control processes of various embodiments of the invention can be implemented in a computer program product tangibly embodied in a machine-readable storage device for execution by a programmable processor; and method steps of various embodiments of the invention can be performed by a programmable processor executing a program of instructions to perform functions of those embodiments of the invention by operating on input data and generating output. The data processes and control processes of various embodiments of the invention can advantageously be implemented in one or more computer programs that are executable on a programmable system including at least one programmable processor coupled to receive data and instructions from, and to transmit data and instructions to, a data storage system, at least one input device, and at least one output device. Each computer program can be implemented in a high-level procedural or object-oriented programming language, or in assembly or machine language if desired; and in any case, the language can be a compiled or interpreted language. Suitable processors include, by way of example, both general and special purpose microprocessors. Generally, a processor will receive instructions and data from a read-only memory and/or a random access memory. Storage devices suitable for tangibly embodying computer program instructions and data include all forms of non-volatile memory, including by way of example semiconductor memory devices, such as EPROM, EEPROM, and flash memory devices; magnetic disks such as internal hard disks and removable disks; magneto-

optical disks; and CD-ROM disks. Any of the foregoing can be supplemented by, or incorporated in, ASICs (application-specific integrated circuits).

The paragraph starting at page 36, line 1 is amended as follows:

To provide for interaction with a user, the data processes and control processes of various embodiments of the invention can be implemented on a computer system having a display device such as a monitor or LCD screen for displaying information to the user and a keyboard and a pointing device such as a mouse or a trackball by which the user can provide input to the computer system. The computer system can be programmed to provide a graphical user interface through which computer programs interact with users.

The paragraph starting at page 36, line 7 is amended as follows:

Other embodiments are [within the claims] possible. Although the above description is directed to planar substrates, the substrate could be non-planar. In such embodiments, the electroplating article can be sufficiently flexible to conform to the shape of the substrate surface, or shaped to match the surface. For example, the electroplating article could be wrapped around a cylindrical substrate. Masking pressure can be applied to nonplanar substrates through a powdered medium that conforms to the mask.

The paragraph starting at page 36, line 13 is amended as follows:

In addition, although the electroplating [methodes] embodiments have been described above with respect to the use of two metals, a variety of materials, e.g., polymers, ceramics and semiconductor materials, and any number of metals can be deposited either by the electroplating [methodes] methods described above, or in separate processes that occur throughout the electroplating method. A thin plating base can be deposited, e.g., by sputtering, over a deposit that is insufficiently conductive (e.g., an insulating layer) so as to enable [continued] subsequent electroplating. Multiple support materials (i.e. sacrificial materials) can be included in the electroplated element allowing selective removal of the support materials.

The paragraph starting at page 36, line 21 is amended as follows:

The electroplating methods of various embodiments of the invention can be used in combination with other processes. Referring to Fig. 31, for example, electromagnetic motor 178 including armature windings 180 connected to an integrated circuit at aluminum pads on

substrate 182, can be formed by interrupting the electroplating method and etching a portion of the support metal (e.g., using a patterned resist) to produce cavity 184 (i.e., the rotor core of the motor) defined by structural metal 186 serving as an etch stop. Cavity 184 is then filled with a magnetic powder (e.g., Ne-Fe-B), which is subsequently sintered and magnetized. If necessary, metal is sputtered onto the sintered magnetic powder to establish a plating base and the electroplating method can be resumed. Such cavities can be filled with solids, fluids or evacuated to form a vacuum.

The paragraph starting at page 37, line 1 is amended as follows:

Where multiple metals are to be deposited, the metals can be selectively deposited on the substrate by masking only the substrate (i.e. any previously formed complete layer). By only masking the substrate, the [The] metal being selectively plated onto the substrate is also deposited onto the previously deposited metals. After each of the metals for a given layer has been deposited the next mask may be used to deposit the next metal for the layer, or more [frequently] preferably, the layer is planarized to the desired thickness after the deposition of each metal prior to deposition of the next metal for the layer. Alternatively, the mask can cover all of the previously deposited metals. [The] In this alternative, the mask can also be stepped in thickness to accommodate the topography of a partially plated substrate.

The paragraph starting at page 37, line 8 is amended as follows:

Another embodiment of the electroplating method involves manufacturing a structure well defined in shape and position according to the following method: preparing a piece of rigid, high strength material with an interconnected porosity (e.g., partly-sintered ceramic); shaping one surface of this piece such that it has the inverse (in the mold making sense) shape to that of the desired deposit; positioning the piece so that its surface lies opposite the substrate to be plated, at the desired position of the final deposit surface, and [place] placing an anode on the other side of it; plating metal onto the substrate while moving the piece (continuously or periodically) with sufficient force and in such a way that its surface still remains matched to that of the desired deposit (for a planar surface, move it within the plane, for a cylindrical surface, move it axially, etc.) (The movement can be a vibration sufficiently large to shear and remove any portion of the deposit that extends into the pores of the piece); continuing plating until the entire volume between the substrate and the piece is filled with the deposit, at which point the deposit will have molded itself to the shape of the piece. The piece

can be disposed of, or periodically reconditioned by chemically flushing the piece with fluid, dissolving the clogging material or placing the clogged surface in contact with an anode and deplating it onto a substrate in an electrolyte.

The paragraph starting at page 37, line 25 is amended as follows:

Referring to Figs. 32a-32d, another embodiment of an electroplating article is shown. Electroplating article 200 includes a mask adhered to and coextensive with a patterned, rigid substrate (e.g., polymethylmethacrylate). During the electroplating method a deposit is formed in the window(s) (i.e., negative mask features) of the article. More specifically, substrate 204 is contacted with a first patterned electroplating article 200, as shown in Fig. 32a; a first metal deposit 206 is formed in a shape defined by the pattern 202 in first electroplating article 200, first article 200 is then removed (Fig. 32b); substrate 204 is then contacted in alignment with a second patterned electroplating article 208 (Fig. 32c), deposit 210 is formed, and second article 208 is removed (Fig. 32d). The plated metal is then planarized and the method repeated until an element of sufficient thickness and dimension has been achieved. The electroplating articles can include a region 210 of overlapping plated metal, which will have a corresponding greater thickness. The overlapping region can be planarized to create a planar layer of deposited metal. Masking pressure can be applied by pressing an anode or porous medium against the electroplating article. The mask can be made stiffer by increasing its thickness.

The paragraph starting at page 38, line 9 is amended as follows:

Although the electroplating [methodes] methods have been described with respect to contacting a cathode with an article and plating onto a cathode, it is contemplated that the electroplating article can be placed in contact with a substrate functioning as an anode such that metal is selectively removed from the anode in a pattern corresponding to the pattern on the electroplating article. Such a process can be employed to selectively etch, engrave, and polish a substrate, e.g., a plaque.

The paragraph starting at page 41, line 2 is amended as follows:

An electroplating method [that] includes[:] forming a layer, the forming of the layer includes: a) contacting a [first] substrate with a first article, the first article [which] includes a [substrate] support and a conformable mask disposed in a pattern on the [substrate] support; b) electroplating a first metal from a source of metal ions onto the [first]substrate in a first

pattern, the first pattern corresponding to the complement of the conformable mask pattern; and c) removing the first article from the [first] substrate[, is disclosed]. The method may further involve one or more of (1) selectively depositing or non-selectively depositing one or more additional materials to complete formation of the layer, (2) planarizing deposited material after each deposition or after all depositions for a layer, and/or (3) forming layers adjacent previously formed layers to build up a structure from a plurality of adhered layers. Electroplating articles and electroplating apparatus are also disclosed.

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ATTACHMENT B

This Response amends the claims as follows:

1. (Canceled)

2. (Canceled)

3. (Amended) A method of making a supported mask, comprising:
obtaining a first support;
forming a surface relief pattern on the first support;
applying a conformable material over the surface relief pattern;
pressing said conformable material using a second support and allowing the conformable material to solidify and to adhere [said conformable material] to said second support;

once said conformable material has adhered to said second support, pulling said second support, with said conformable material adhered thereto, away from said first support[,] to leave a patterned area in the conformable material that is based on said surface relief pattern[,] and to leave said first support.

4. (Amended) The [A] method as in claim 3, wherein said conformable material includes an elastomer.

5. (Amended) The [A] method as in claim 3, further comprising etching indented areas which are formed by contact with said surface relief areas, said etching continuing until said indented areas extend through to said second support.

6. (Amended) The [A] method as in claim 3, where said second support is porous, and further comprising initially blocking pores prior to said pressing of said second support, and unblocking the pores after said pulling.

7. (Amended) A method of making a supported mask, comprising:
obtaining a support;
applying at least one layer of dielectric material to said support; and
exposing said layer to patterned light to substantially [the remove] cause removal of said layer from said support in exposed areas.

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The following claims have been added:

8. (New) The method as in claim 7 wherein the patterned light is UV light.
9. (New) The method as in claim 7 wherein the exposing causes ablation of the exposed areas of the layer.
10. (New) A method of making a supported mask, comprising:
 - providing a support;
 - forming a surface relief pattern on a surface of the support, wherein the pattern has positive and negative features;
 - applying a flowable conformable material over the surface of the support containing the relief pattern;
 - pressing the flowable conformable material against the surface of the support to remove at least a portion of any conformable material that is located over positive features of the surface relief pattern;
 - solidifying and bonding the flowable conformable material to the support;
 - removing any residual conformable material that is located over the positive features of the surface relief pattern; and
 - removing the surface relief pattern from the support while leaving the solidified conformable material bonded to the support.
11. (New) The method as in claim 10, wherein a flat, non-stick sheet is used to press the conformable material.
12. (New) The method as in claim 10, wherein the residual conformable material is removed by etching.
13. (New) The method as in claim 10, wherein the support comprises a porous medium.
14. (New) The method as in claim 13, further comprising:
 - forming a barrier layer on the support prior to forming the surface relief pattern; and
 - removing the barrier layer from at least selected areas of the support.